Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	401	349/43 and pad and expos$4	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/15 13:32
L2	155	349/152 and pad and expos$4	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/15 13:32
L3	96	349/143 and pad and expos$4 and mask$4	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/15 13:33
L4	86	349/150 and pad and expos$4	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/15 13:33
L5	80	349/152 and pad and expos$4 and mask$4	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/15 13:33
S48	927	349/149	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/15 13:31
S49	963	349/187	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/05/19 15:29
S50	27	cutting-off adj plate	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/05/19 15:37

S51	4883	expos$4 near10 pad near10 etch$4	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/05/19 15:38
S52	237	(expos$4 near10 pad near10 etch$4) and gate and data and semiconductor and pixel and mask$4	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/05/23 11:15

| S53 | 239 | ("1954691" \| "2851408" \| "2867541" \| "2959483" \| "3070441" \| "3108904" \| "3259782" \| "3314871" \| "3360450" \| "3525679" \| "3554889" \| "3665241" \| "3675063" \| "3755704" \| "3789471" \| "3808048" \| "3812559" \| "3855499" \| "3898146" \| "3947716" \| "3970887" \| "3998678" \| "4008412" \| "4075535" \| "4084942" \| "4139773" \| "4141405" \| "4143292" \| "4164680" \| "4168213" \| "4178531" \| "4307507" \| "4350926" \| "4482447" \| "4498952" \| "4507562" \| "4512912" \| "4513308" \| "4540983" \| "4542038" \| "4578614" \| "4588921" \| "4594527" \| "4633131" \| "4647400" \| "4663559" \| "4684353" \| "4684540" \| "4685996" \| "4687825" \| "4687938" \| "4710765" \| "4721885" \| "4728851" \| "4758449" \| "4763187" \| "4780684" \| "4788472" \| "4816717" \| "4818914" \| "4822466" \| "4827177" \| "4835438" \| "4851254" \| "4855636" \| "4857161" \| "4857799" \| "4874981" \| "4882659" \| "4889690" \| "4892757" \| "4899081" \| "4900584" \| "4908539" \| "4923421" \| "4926056" \| "4933108" \| "4940916" \| "4943343" \| "4956202" \| "4956574" \| "4964946" \| "4987007" \| "4990416" \| "4990766" \| "4994205" \| "5007873" \| "5015912" \| "5019003" \| "5036247" \| "5038070" \| "5043715" \| "5054046" \| "5054047" \| "5055077" \| "5055744" \| "5057047" \| "5063323" \| "5063327" \| "5064396" \| "5066883" \| "5075591" \| "5075595" \| "5075596" \| "5079476" \| "5085958" \| "5089292" \| "5089742" \| "5089812" \| "5090932" \| "5098737" \| "5101137" \| "5101288" \| "5103144" \| "5103145" \| "5117267" \| "5117299" \| "5119386" \| "5123039" \| "5124072" \| "5124558" \| "5126287" \| "5129850" \| "5132585" \| "5132676").PN. OR ("5136764" \| "5138237" \| "5140219" \| "5141459" \| "5141460" \| "5142184" \| "5142256" \| "5142390" \| "5144191" \| "5148078" \| "5148461" \| "5150011" \| "5150192" \| "5151061" \| "5153753" \| "5153901" \| "5155420" \| "5156770" \| "5157304" \| "5157309" \| "5162704" \| "5166456" \| "5173634" \| "5173635" \| "5173697" \| "5180951" \| "5183529" \| "5185178" \| "5186670" \| "5187578" \| "5191217" \| "5192240" \| "5194780" \| "5199917" \| "5199918" \| "5201992" \| "5202571" \| "5203731" \| "5204021" \| "5204581" \| "5205770" \| "5209687" \| "5210430" \| "5210462" \| "5212426" \| "5213712" \| "5214346" \| "5214347" \| "5214416" \| "5220923" \| "5227699" \| "5228877" \| "5228878" \| "5229331" \| "5229682" \| "5231606" \| "5232549" | US-PGPUB; USPAT; USOCR | OR | OFF | 2005/05/19 16:28 |

S54	24	(expos$4 near10 pad near10 (dry adj etch$4)) and gate and data and semiconductor and pixel and mask$4	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/05/19 16:29
S55	94	(expos$4 near10 pad near10 etch$4) and gate and data and semiconductor and pixel and mask$4 and cut$4	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/05/20 11:08
S56	2	(expos$4 near10 pad near10 etch$4) and gate and data and semiconductor and pixel and mask$4 and cut$4-off	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/05/20 11:08
S57	998	349/143	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/05/21 10:24
S58	367	349/150	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/05/21 10:24
S59	1653	349/43	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/05/21 10:25
S60	357	349/43 and pad and expos$4	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/15 13:32
S61	73	349/150 and pad and expos$4	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/15 13:33

S62	131	349/152 and pad and expos$4	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/15 13:32
S63	114	349/143 and pad and expos$4	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/05/21 10:37
S65	84	349/143 and pad and expos$4 and mask$4	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/15 13:33
S67	66	349/152 and pad and expos$4 and mask$4	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/15 13:33
S69	291	349/43 and pad and expos$4 and mask$4	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/05/21 10:39
S70	111	(expos$4 near10 pad near10 etch$4) and gate and data and semiconductor and pixel and mask$4 and ((mask cutting-off) near10 metal)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/05/23 17:08
S71	9	(expos$4 near10 pad near10 etch$4) and gate and data and semiconductor and pixel and mask$4 and ((mask cutting-off) near10 metal) and ((three "3") adj mask$4)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/05/23 12:54
S72	1857216	(dry adj etch$4) nea10 insulat$4	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/05/23 17:11

S73	4990943	S72 (liquid adh crystal)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/05/23 17:10
S74	2348219	S72 (liquid adh crystal) and expos$4	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/05/23 17:10
S75	150088	(dry adj etch$4) nea10 insulat$4 near10 expos$4	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/05/23 17:15
S76	11537	S75 and (liquid adj crystal)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/05/23 17:12
S77	2992	(S75 near10 remov$4)and (liquid adj crystal)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/05/23 17:13
S78	833	(S75 near10 remov$4)and (liquid adj crystal) and pad	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/05/23 17:13
S79	228	(S75 near10 remov$4)and (liquid adj crystal) and (gate adj pad) and (data adj pad)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/05/23 17:14
S80	1281	(dry adj etch$4) near10 insulat$4 near10 expos$4	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/05/23 17:15

| S81 | 40 | (dry adj etch$4) near10 insulat$4 near10 expos$4 and (gate adj pad) and (data adj pad) | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2005/05/23 17:16 |